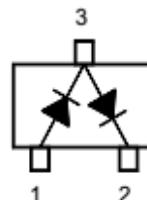
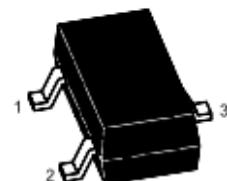


Switching Diode

Features

- For surface mount applications
- Fast reverse recovery time
- Ideal for automated placement

SOT-23



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	85	V
Continuous reverse voltage	V_R	75	V
Continuous forward current (double diode load)	I_F	125	mA
Continuous forward current (single diode load)	I_F	215	mA
Repetitive Peak Forward Current	I_{FRM}	450	mA
Peak Forward Surge Current at t= 1s t=1ms t= μ s	I_{FSM}	0.5 1 4.5	A
Repetitive Peak Forward Current	I_{FRM}		V
Forward Voltage at $I_F=1$ mA $I_F=10$ mA $I_F=50$ mA $I_F=150$ mA	V_F	0.715 0.855 1 1.25	V
Reverse Current at $V_R=25$ V $V_R=75$ V $V_R=25$ V, $T_J=150^\circ\text{C}$ $V_R=75$ V, $T_J=150^\circ\text{C}$	I_R	30 1 30 50	nA μ A μ A μ A
Typical Junction Capacitance $V_R=4$ V, $f=1$ MHz	C_J	1.5	pF
Power Dissipation	P_D	350	mW
Maximum Reverse Recovery Time	T_{rr}	4	nS
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^\circ\text{C}$

Electrical Characteristics Curves

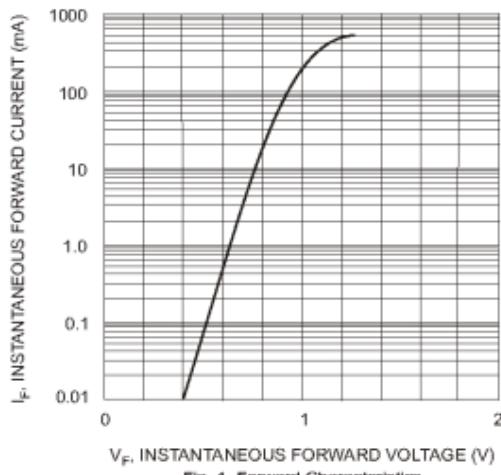


Fig. 1 Forward Characteristics

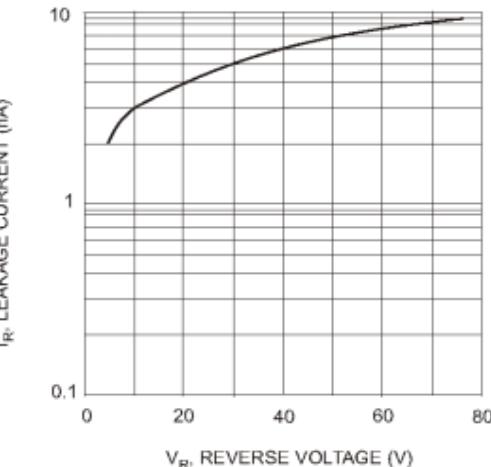


Fig. 2 Typical Leakage Current vs Reverse Voltage

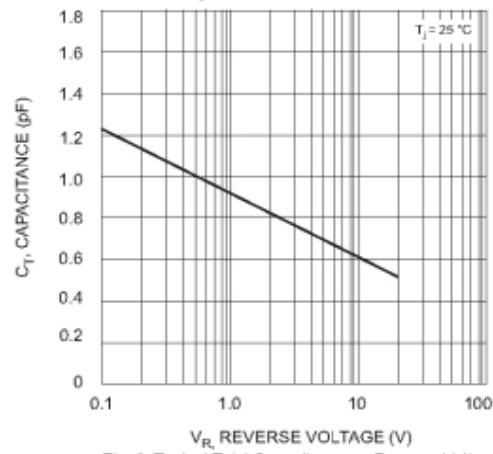
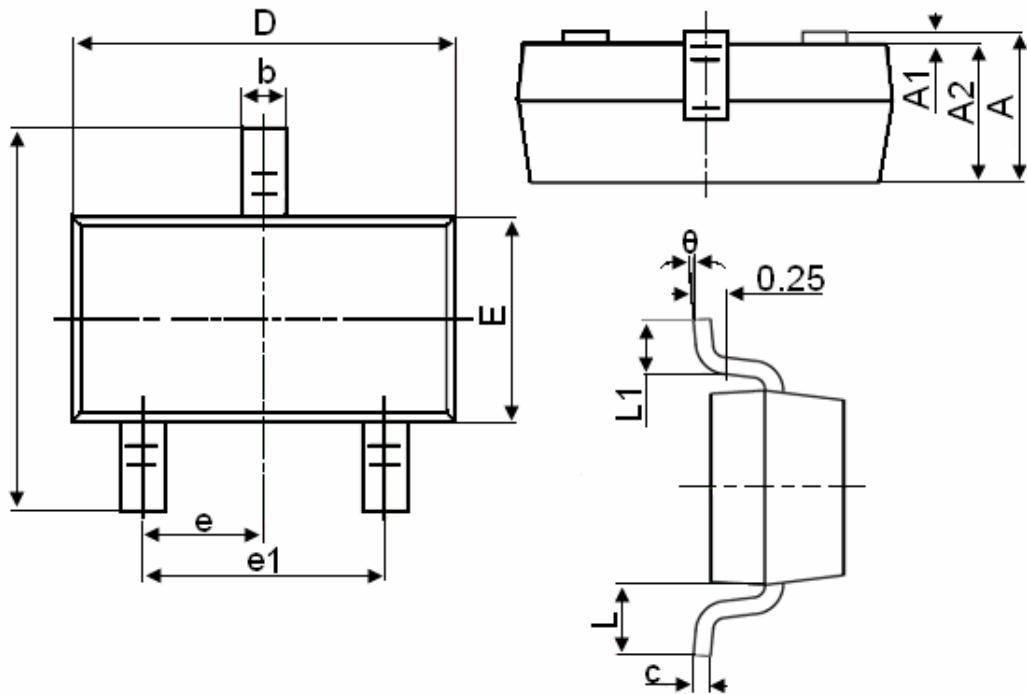


Fig. 3 Typical Total Capacitance vs Reverse Voltage

SOT-23 Package Information

Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°